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LEE et al.(10) **Pub. No.: US 2019/0140039 A1**(43) **Pub. Date: May 9, 2019**(54) **ORGANIC LIGHT EMITTING DIODE
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KIM**, Paju-si (KR); **Jaesung LEE**,
Paju-si (KR)(73) Assignee: **LG Display Co., Ltd.**, Seoul (KR)(21) Appl. No.: **16/181,791**(22) Filed: **Nov. 6, 2018**(30) **Foreign Application Priority Data**

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(57)

ABSTRACT

An organic light emitting diode display is disclosed. The organic light emitting diode display includes a first substrate including an organic light emitting diode, a second substrate including a power line supplied with a power voltage and facing the first substrate, and a conductive filler layer between the first substrate and the second substrate. The first substrate includes an auxiliary electrode, a first barrier on the auxiliary electrode, a cathode physically divided by the first barrier and exposing at least a portion of the auxiliary electrode, a contact electrode disposed on the cathode, physically divided by the first barrier, and exposing at least a portion of the auxiliary electrode, and a protective layer between the cathode and the contact electrode. One end of the cathode directly contacts the auxiliary electrode, and one end of the contact electrode directly contacts the auxiliary electrode.

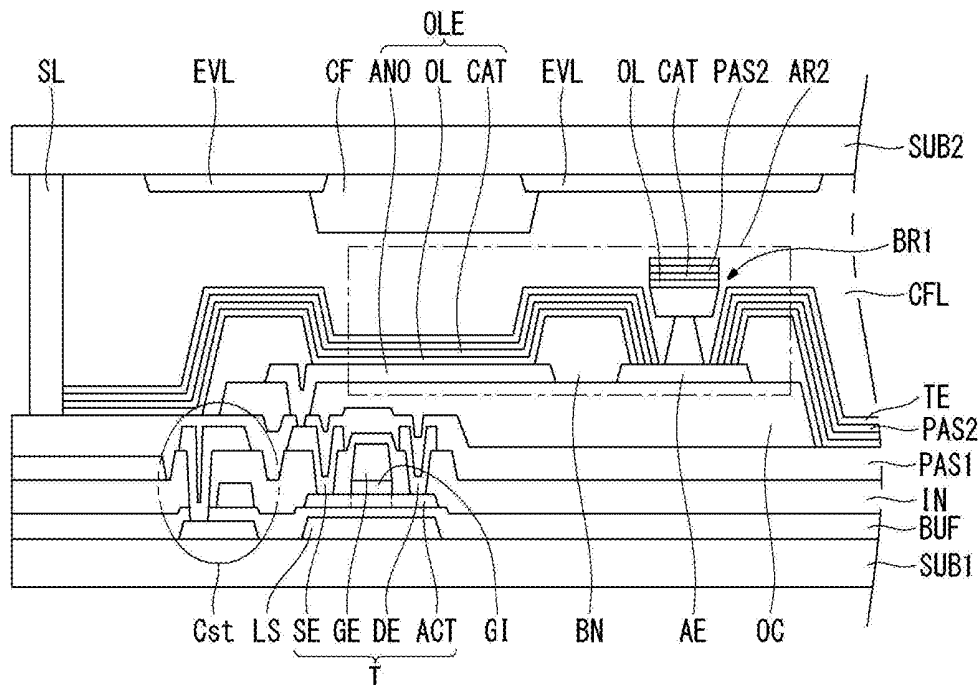


FIG. 1

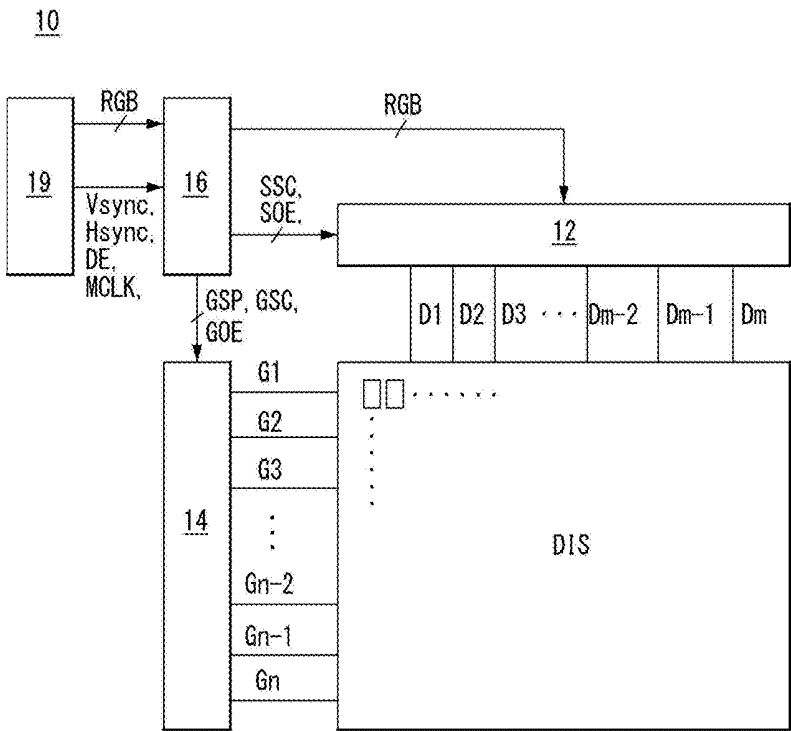


FIG. 2

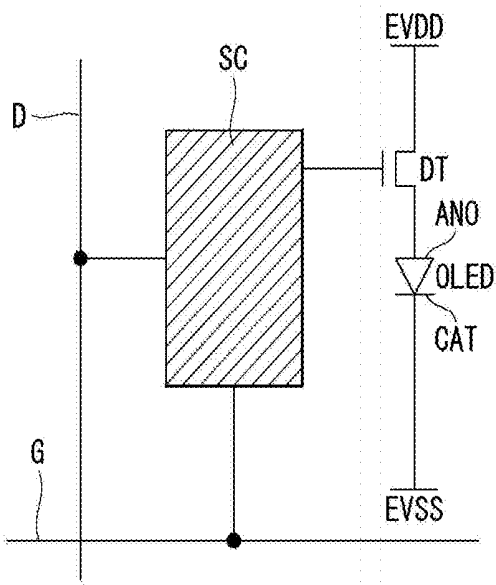


FIG. 3

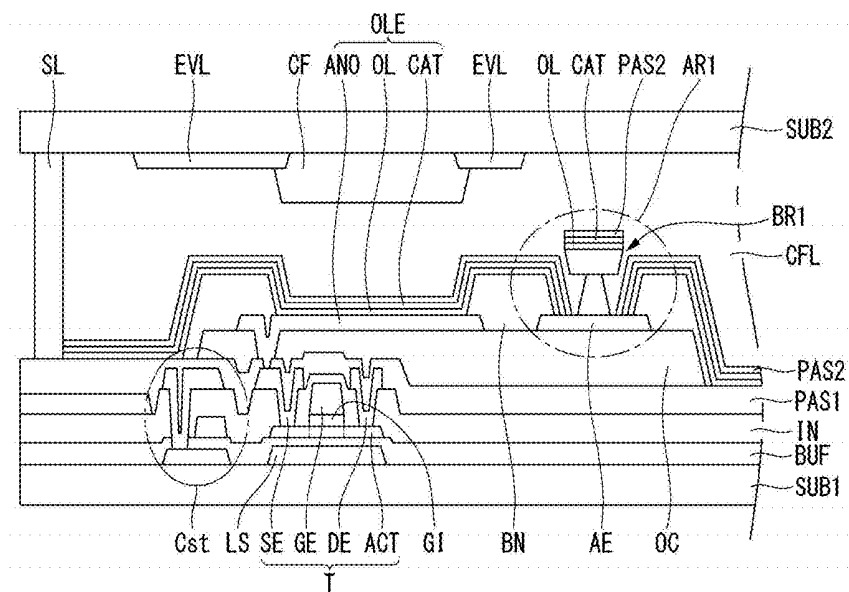


FIG. 4

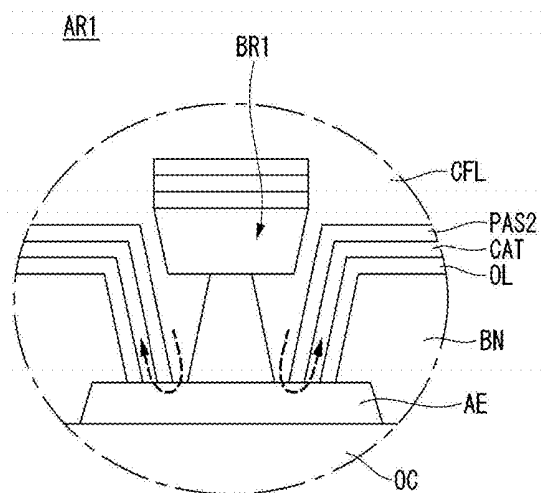


FIG. 5

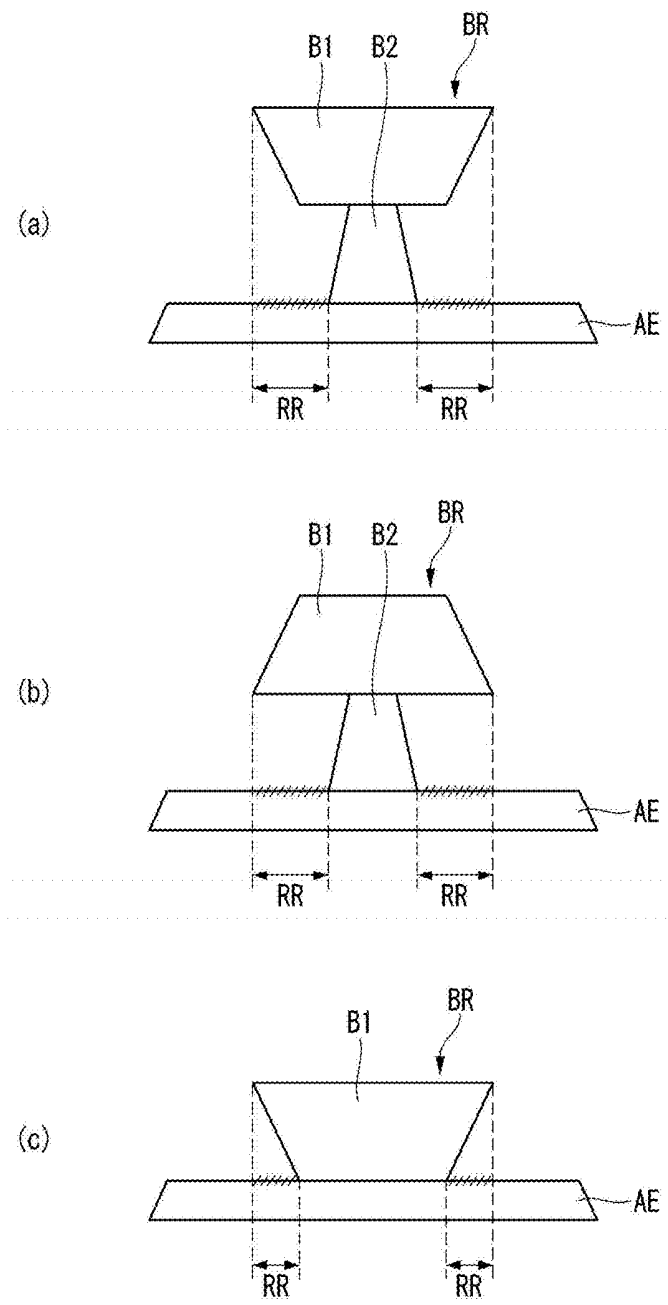


FIG. 6

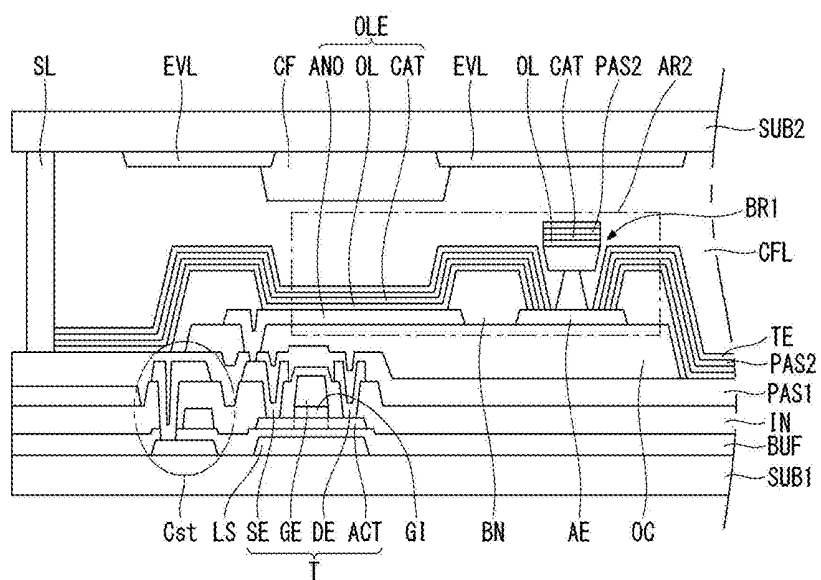
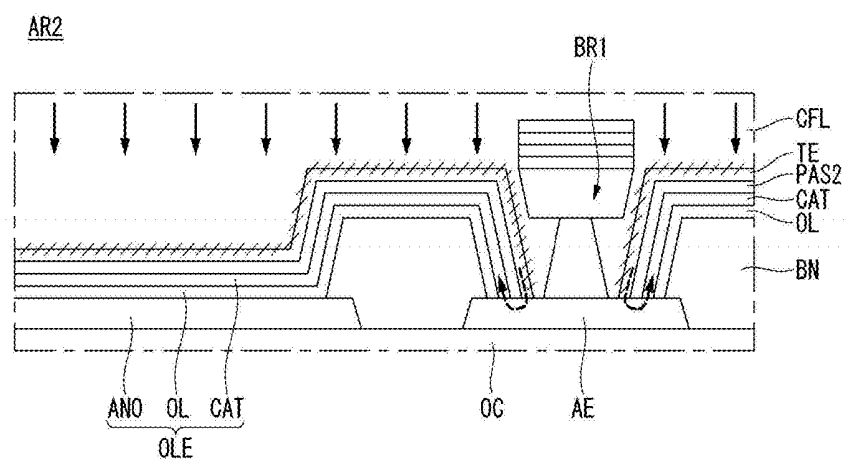


FIG. 7



Path1 : CFL → AE → CAT

Path2 : CFL → TE → AE → CAT

FIG. 8

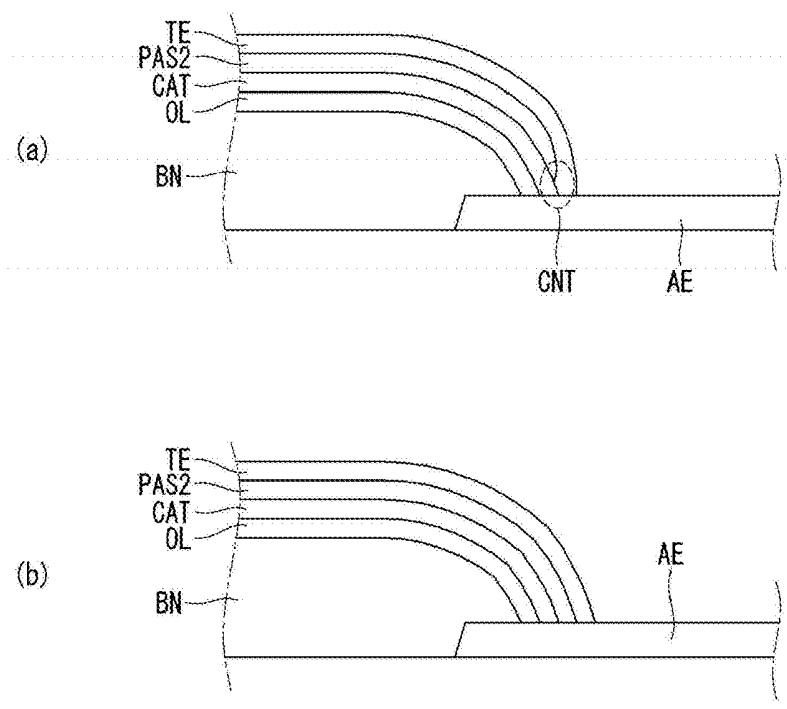


FIG. 9

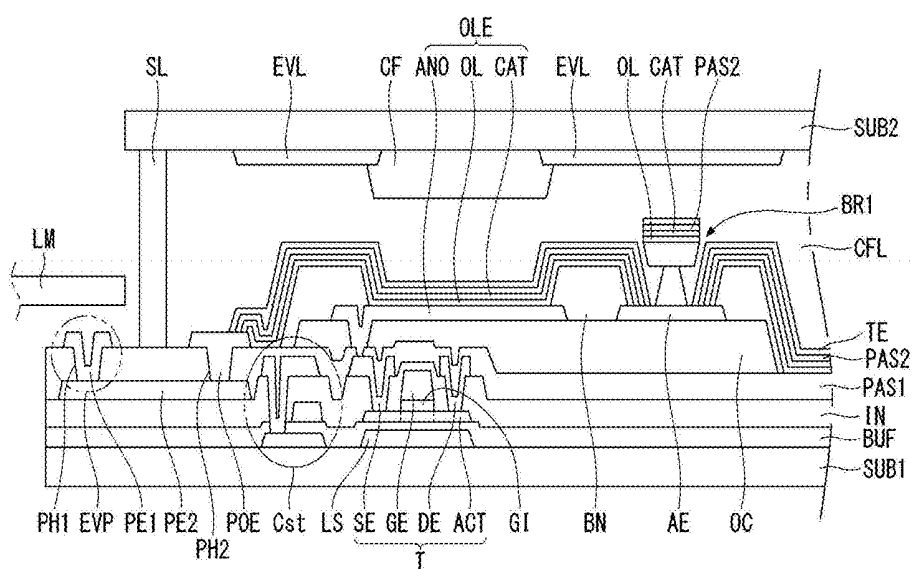


FIG. 10

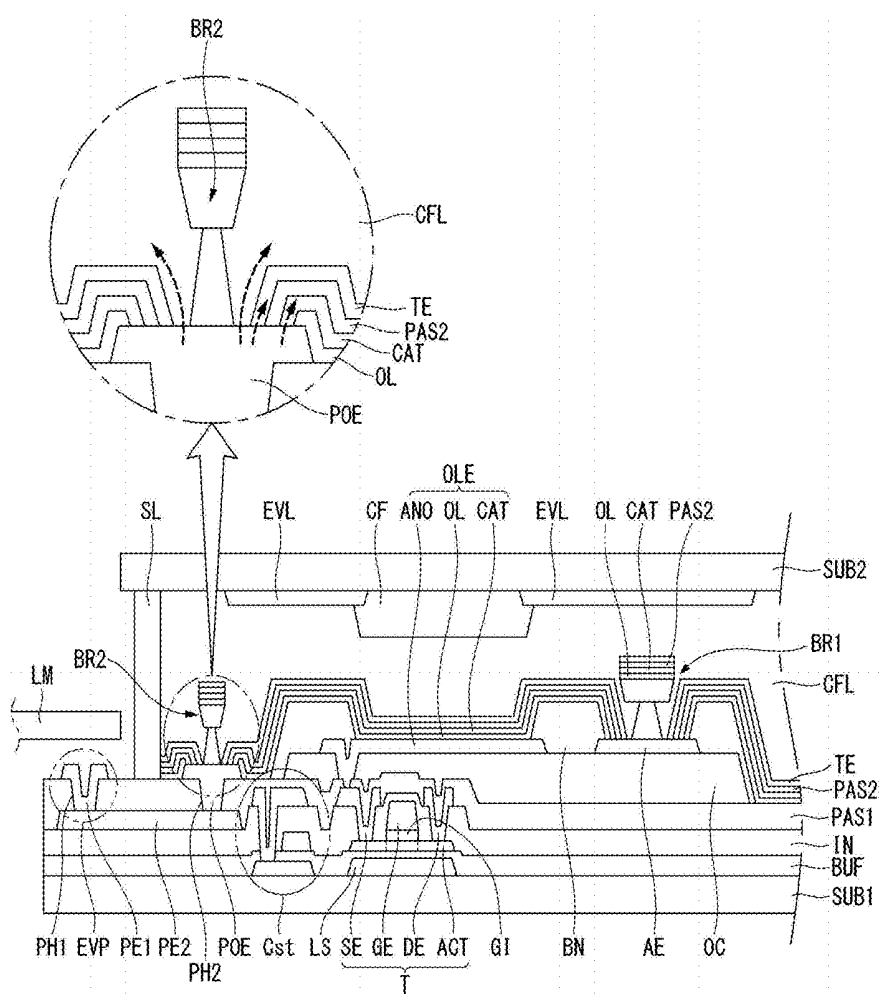


FIG. 11

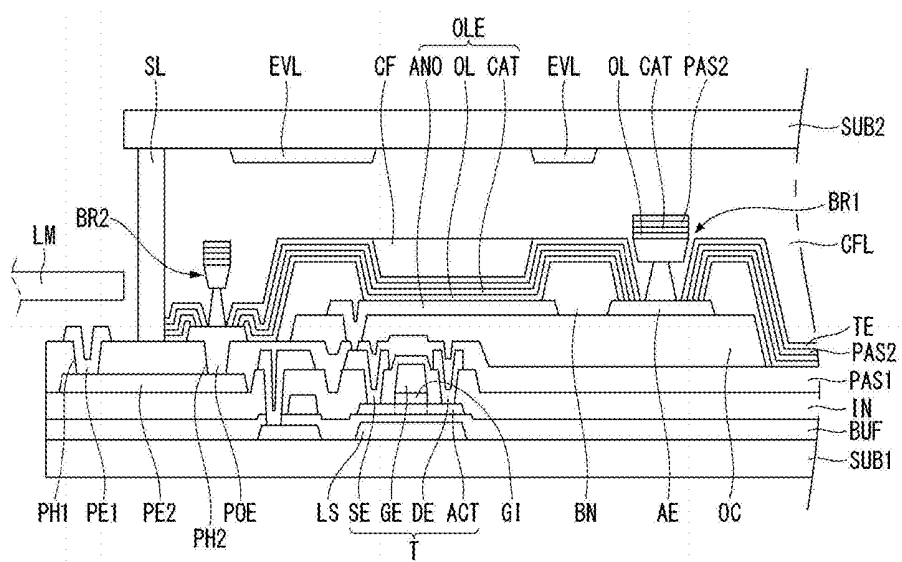


FIG. 12

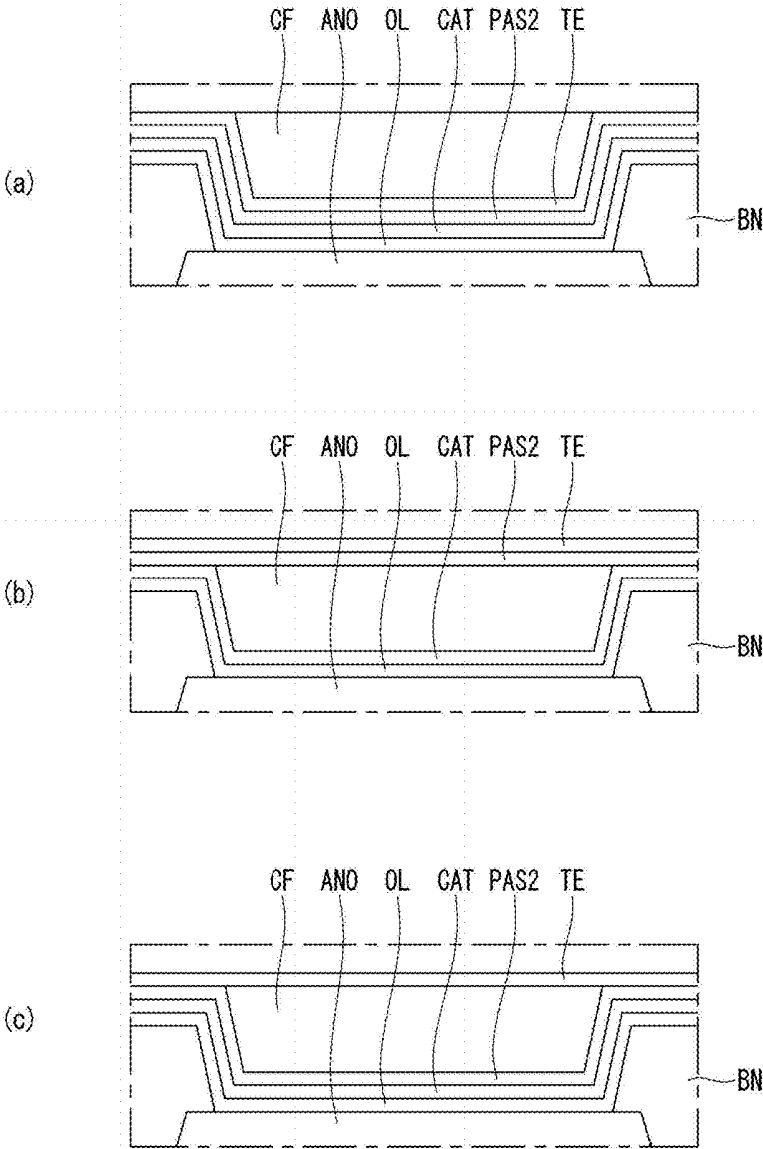
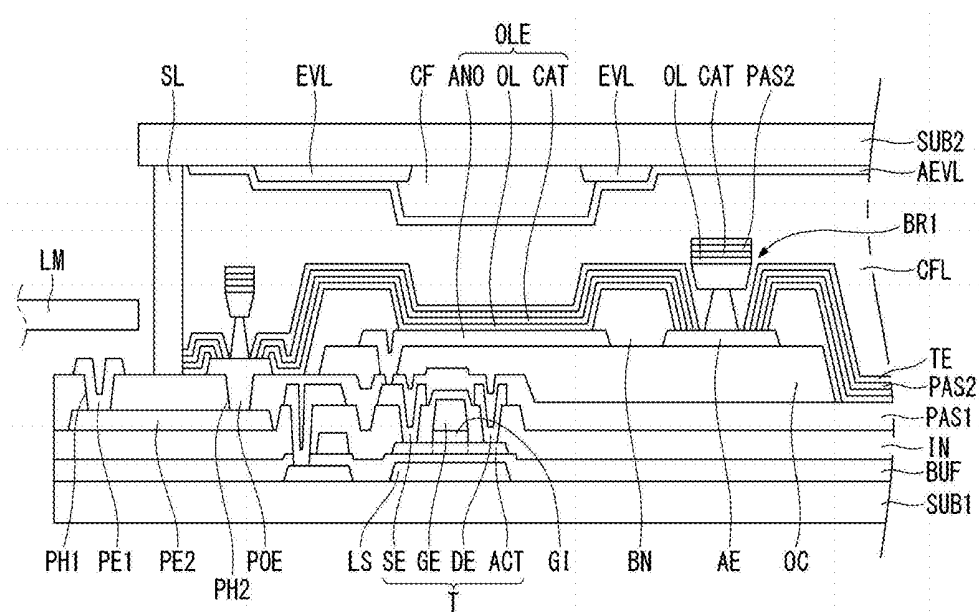


FIG. 13



ORGANIC LIGHT EMITTING DIODE DISPLAY

[0001] This application claims the priority benefit of Korean Patent Application No. 10-2017-0147582 filed on Nov. 7, 2017, which is incorporated herein by reference for all purposes as if fully set forth herein.

BACKGROUND

Technical Field

[0002] The present disclosure relates to an organic light emitting diode display.

Discussion of the Related Art

[0003] Various display devices have replaced heavier and larger cathode ray tubes (CRTs). Examples of the display devices may include a liquid crystal display (LCD), a field emission display (FED), a plasma display panel (PDP), and an organic light emitting diode (OLED) display.

[0004] In more detail, an OLED display is a self-emission display configured to emit light by exciting an organic compound. The OLED display does not require a backlight unit used in a liquid crystal display and thus has advantages of a thin profile, lightness in weight, and a simpler manufacturing process. The OLED display can be also manufactured at a low temperature and has a fast response time of 1 ms or less, low power consumption, a wide viewing angle, and a high contrast. Thus, the OLED display has been widely used.

[0005] The OLED display includes organic light emitting diodes (OLEDs) converting electric energy into light energy. The OLED includes an anode, a cathode, and an organic emission layer between the anode and the cathode. The OLED display is configured such that the OLED emits light while excitons formed by combining holes from the anode and electrons from the cathode inside an emission layer fall from an excited state to a ground state, and thus displays an image.

[0006] However, a large-area OLED display cannot maintain a uniform luminance throughout an entire surface of an active area, on which an input image is displayed, and generates a luminance variation (or luminance deviation) depending on a position. More specifically, a cathode constituting an organic light emitting diode is formed to cover most of the active area, and there is a problem that a power voltage applied to the cathode does not have a constant voltage value throughout the entire surface of the active area. For example, as a difference between a voltage value at an entrance of the cathode supplied with the power voltage and a voltage value at a position apart from the entrance increases due to a resistance of the cathode, the luminance variation depending on the position increases.

[0007] The problem is more problematic in a top emission type display device. Namely, in the top emission type display device, because it is necessary to secure a transmittance of a cathode positioned at an upper layer of an organic light emitting diode, the cathode is formed of a transparent conductive material such as indium tin oxide (ITO), or an opaque conductive material with a very small thickness. In this instance, because a surface resistance of the cathode increases, a luminance variation depending on a position remarkably increases corresponding to an increase in the surface resistance.

[0008] In order to solve such a problem, a method was proposed to prevent a voltage drop depending on a position by forming a low potential power voltage line including a low resistance material and connecting the low potential power voltage line to a cathode. In the proposed method according to a related art, because the low potential power voltage line was formed on a lower substrate including transistors, one pixel has to further include a connection area of the low potential power voltage line and the cathode in addition to a thin film transistor area and a storage capacitor area. Thus, it was difficult to apply the related art to a high-resolution display including small-sized unit pixels.

SUMMARY

[0009] Accordingly, embodiments of the present disclosure are directed to an organic light emitting diode display that substantially obviates one or more of the problems due to limitations and disadvantages of the related art.

[0010] An aspect of the present disclosure is to provide an organic light emitting diode display capable of achieving a uniform luminance by reducing a variation in a low potential power voltage depending on a position.

[0011] Additional features and aspects will be set forth in the description that follows, and in part will be apparent from the description, or may be learned by practice of the inventive concepts provided herein. Other features and aspects of the inventive concepts may be realized and attained by the structure particularly pointed out in the written description, or derivable therefrom, and the claims hereof as well as the appended drawings.

[0012] To achieve these and other aspects of the inventive concepts, as embodied and broadly described, an organic light emitting diode display comprises a first substrate including an organic light emitting diode, a second substrate including a power line supplied with a power voltage, the second substrate facing the first substrate, and a conductive filler layer interposed between the first substrate and the second substrate, the conductive filler layer including a conductive medium, wherein the first substrate includes an auxiliary electrode, a first barrier disposed on the auxiliary electrode, a cathode included in the organic light emitting diode and physically divided by the first barrier, the cathode exposing at least a portion of the auxiliary electrode, one end of the cathode directly contacting the auxiliary electrode, a contact electrode disposed on the cathode and physically divided by the first barrier, the contact electrode exposing at least a portion of the auxiliary electrode, one end of the contact electrode directly contacting the auxiliary electrode, and a protective layer interposed between the cathode and the contact electrode.

[0013] The contact electrode directly contacts the conductive filler layer and is electrically connected to the cathode through the auxiliary electrode.

[0014] The protective layer on the cathode exposes at least a portion of one end of the cathode. The contact electrode on the protective layer directly contacts the exposed portion of the cathode.

[0015] The cathode and the contact electrode are spaced from each other with the protective layer interposed therebetween.

[0016] The conductive filler layer directly contacts the exposed portion of the auxiliary electrode.

[0017] The organic light emitting diode display further comprises a sealant disposed at an edge of the first substrate

and an edge of the second substrate, the conductive filler layer being accommodated inside the sealant, and a power electrode disposed on the first substrate and inside the sealant, the power electrode receiving the power voltage from a power generator. At least a portion of the power electrode directly contacts the conductive filler layer. The power electrode is electrically connected to the power line through the conductive filler layer.

[0018] The organic light emitting diode display further comprises a sealant disposed at an edge of the first substrate and an edge of the second substrate, the conductive filler layer being accommodated inside the sealant, a power electrode disposed on the first substrate and inside the sealant, the power electrode receiving the power voltage from a power generator, and a second barrier disposed on the power electrode. The cathode is divided by the second barrier and exposes at least a portion of the power electrode. The protective layer is divided by the second barrier and exposes at least a portion of the power electrode. The contact electrode is divided by the second barrier and exposes at least a portion of the power electrode. The power electrode is electrically connected to an exposed portion of the power line through the conductive filler layer.

[0019] One end of the cathode directly contacts the power electrode. One end of the contact electrode directly contacts the power electrode.

[0020] The second substrate further includes color filters. The color filters are partitioned by the power line.

[0021] The first substrate further includes color filters respectively assigned to pixels. The color filters are disposed on the contact electrode.

[0022] The first substrate further includes color filters respectively assigned to pixels. The color filters are interposed between the cathode and the protective layer.

[0023] The first substrate further includes color filters respectively assigned to pixels. The color filters are interposed between the protective layer and the contact electrode.

[0024] Each of the first substrate and the second substrate includes an emission region, to which light from the organic light emitting diode is emitted, and a non-emission region outside the emission region. The power line is disposed in the non-emission region.

[0025] The second substrate further includes an auxiliary power line, of which at least a portion of one surface directly contacts the power line, and another surface opposite the one surface directly contacts the conductive filler layer.

[0026] The auxiliary power line has an area larger than the power line.

[0027] The auxiliary power line includes a transparent conductive material.

[0028] It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the inventive concepts as claimed.

BRIEF DESCRIPTION OF THE DRAWINGS

[0029] The accompanying drawings, that may be included to provide a further understanding of the disclosure and are incorporated in and constitute a part of this application, illustrate embodiments of the disclosure and together with the description serve to explain various principles.

[0030] FIG. 1 is a block diagram schematically illustrating an organic light emitting diode (OLED) display according to an embodiment of the disclosure.

[0031] FIG. 2 schematically illustrates configuration of a pixel shown in FIG. 1.

[0032] FIG. 3 is a cross-sectional view of an OLED display according to a first embodiment of the disclosure.

[0033] FIG. 4 is an enlarged view of an area AR1 shown in FIG. 3.

[0034] FIG. 5 is cross-sectional views schematically illustrating a shape of a barrier.

[0035] FIG. 6 is a cross-sectional view of an OLED display according to a second embodiment of the disclosure.

[0036] FIG. 7 is an enlarged view of an area AR2 shown in FIG. 6.

[0037] FIG. 8 illustrates a position relationship of a cathode, a protective layer, and a contact electrode.

[0038] FIGS. 9 and 10 illustrate an example of configuration of a power supply unit.

[0039] FIG. 11 is a cross-sectional view of an OLED display according to a third embodiment of the disclosure.

[0040] FIG. 12 illustrates examples of configuration in which a color filter is formed on a first substrate.

[0041] FIG. 13 is a cross-sectional view of an OLED display according to a fourth embodiment of the disclosure.

DETAILED DESCRIPTION

[0042] Reference will now be made in detail to embodiments of the disclosure, examples of which are illustrated in the accompanying drawings. Wherever possible, the same reference numbers will be used throughout the drawings to refer to the same or like parts. Detailed descriptions of known arts will be omitted if such may mislead the embodiments of the disclosure. In describing various embodiments, the same components may be described in a first embodiment, and a description thereof may be omitted in other embodiments.

[0043] The terms “first”, “second”, etc. may be used to describe various components, but the components are not limited by such terms. The terms are used only for the purpose of distinguishing one component from other components.

[0044] FIG. 1 is a block diagram schematically illustrating an organic light emitting diode (OLED) display according to an embodiment of the disclosure. FIG. 2 schematically illustrates configuration of a pixel shown in FIG. 1.

[0045] Referring to FIG. 1, an OLED display 10 according to an embodiment of the disclosure includes a display driving circuit and a display panel DIS.

[0046] The display driving circuit includes a data driving circuit 12, a gate driving circuit 14, and a timing controller 16. The display driving circuit applies a video data voltage of an input image to pixels of the display panel DIS. The data driving circuit 12 converts digital video data RGB received from the timing controller 16 into an analog gamma compensation voltage and generates a data voltage. The data voltage output from the data driving circuit 12 is supplied to data lines D1 to Dm, where m is a positive integer. The gate driving circuit 14 sequentially supplies a gate signal synchronized with the data voltage to gate lines G1 to Gn and selects pixels of the display panel DIS to which the data voltage is applied, where n is a positive integer.

[0047] The timing controller 16 receives timing signals, such as a vertical sync signal Vsync, a horizontal sync signal Hsync, a data enable signal DE, and a main clock MCLK, from a host system 19 and synchronizes operation timing of the data driving circuit 12 with operation timing of the gate

driving circuit **14**. A data timing control signal for controlling the data driving circuit **12** includes a source sampling clock SSC, a source output enable signal SOE, and the like. A gate timing control signal for controlling the gate driving circuit **14** includes a gate start pulse GSP, a gate shift clock GSC, a gate output enable signal GOE, and the like.

[0048] The host system **19** may be one of a television system, a set-top box, a navigation system, a DVD player, a Blu-ray player, a personal computer (PC), a home theater system, a phone system, and other systems that include or operate in conjunction with a display. The host system **19** includes a system-on chip (SoC), in which a scaler is embedded, and converts the digital video data RGB of the input image into a format suitable for displaying the input image on the display panel DIS. The host system **19** transmits the digital video data RGB of the input image and the timing signals Vsync, Hsync, DE and MCLK to the timing controller **16**.

[0049] The display panel DIS includes a pixel array. The pixel array includes the pixels defined by the data lines D1 to Dm and the gate lines G1 to Gn. Each pixel includes an organic light emitting diode serving as a self-emission element.

[0050] Referring to FIG. 2, the display panel DIS includes a plurality of data lines D, a plurality of gate lines G intersecting the data lines D, and pixels respectively arranged at intersections of the data lines D and the gate lines G in a matrix. Each pixel includes an organic light emitting diode, a driving thin film transistor (TFT) DT for controlling an amount of current flowing through the organic light emitting diode, and a programming unit SC for setting a gate-to-source voltage of the driving thin film transistor DT.

[0051] The programming unit SC may include at least one switching thin film transistor and at least one storage capacitor. The switching thin film transistor is turned on in response to a gate signal from the gate line G to thereby apply a data voltage from the data line D to one electrode of the storage capacitor. The driving thin film transistor DT controls an amount of current supplied to the organic light emitting diode depending on a magnitude of voltage stored in the storage capacitor, thereby controlling an amount of light emitted by the organic light emitting diode. The amount of light emitted by the organic light emitting diode is proportional to the amount of current supplied from the driving thin film transistor DT. The pixel is connected to a high potential power voltage source and a low potential power voltage source and receives a high potential power voltage EVDD and a low potential power voltage EVSS from a power generator (not shown). The thin film transistors constituting the pixel may be p-type thin film transistors or n-type thin film transistors. Further, semiconductor layers of the thin film transistors constituting the pixel may include amorphous silicon, polycrystalline silicon, or oxide. In the following description, embodiments of the disclosure use a semiconductor layer including oxide as an example. The organic light emitting diode includes an anode ANO, a cathode CAT, and an organic light emitting layer between the anode ANO and the cathode CAT. The anode ANO is connected to the driving thin film transistor DT.

First Embodiment

[0052] FIG. 3 is a cross-sectional view of an OLED display according to a first embodiment of the disclosure. FIG. 4 is an enlarged view of an area AR1 shown in FIG. 3.

[0053] Referring to FIG. 3, an OLED display according to a first embodiment of the disclosure includes a display panel including a first substrate SUB1 and a second substrate SUB2 facing each other and a conductive filler layer CFL between the first substrate SUB1 and the second substrate SUB2. The first substrate SUB1 is a thin film transistor array substrate on which a thin film transistor T and an organic light emitting diode OLE are disposed. The second substrate SUB2 is a substrate on which a low potential power voltage line (hereinafter referred to as "Evss line") EVL is disposed. The second substrate SUB2 may function as an encapsulation substrate. The first substrate SUB1 and the second substrate SUB2 may be attached to each other using a sealant SL. The sealant SL is disposed at an edge of the first substrate SUB1 and an edge of the second substrate SUB2 and maintains a predetermined attachment distance between the first substrate SUB1 and the second substrate SUB2. The conductive filler layer CFL may be disposed inside the sealant SL.

[0054] The first substrate SUB1 may be made of glass material or plastic material. For example, the first substrate SUB1 may be made of plastic material such as polyimide (PI), polyethylene terephthalate (PET), polyethylene naphthalate (PEN), and polycarbonate (PC) and may have flexible characteristics.

[0055] The thin film transistor T and the organic light emitting diode OLE connected to the thin film transistor T are formed on the first substrate SUB1. A light shielding layer LS and a buffer layer BUF may be formed between the first substrate SUB1 and the thin film transistor T. The light shielding layer LS is disposed to overlap a semiconductor layer, particularly, a channel of the thin film transistor T and can protect an oxide semiconductor element from external light. The buffer layer BUF can block ions or impurities diffused from the first substrate SUB1 and also block moisture penetration from the outside.

[0056] The thin film transistor T includes a semiconductor layer ACT, a gate electrode GE, a source electrode SE, and a drain electrode DE.

[0057] A gate insulating layer GI and the gate electrode GE are disposed on the semiconductor layer ACT. The gate insulating layer GI functions to insulate the gate electrode GE and may be formed of silicon oxide (SiOx). However, embodiments are not limited thereto. The gate electrode GE is disposed to overlap the semiconductor layer ACT with the gate insulating layer GI interposed therebetween. The gate electrode GE may be formed as a single layer or a multilayer using copper (Cu), molybdenum (Mo), aluminum (Al), chrome (Cr), gold (Au), titanium (Ti), nickel (Ni), neodymium (Nd), tantalum (Ta), tungsten (W), or a combination thereof. The gate insulating layer GI and the gate electrode GE may be patterned using the same mask. In this instance, the gate insulating layer GI and the gate electrode GE may have the same area. Although not shown, the gate insulating layer GI may be formed to cover the entire surface of the first substrate SUB1.

[0058] An interlayer dielectric layer IN is positioned on the gate electrode GE. The interlayer dielectric layer IN functions to insulate the gate electrode GE and the source and drain electrodes SE and DE from each other. The

interlayer dielectric layer IN may be formed of silicon oxide (SiO_x), silicon nitride (SiN_x), or a multilayer thereof. However, embodiments are not limited thereto.

[0059] The source electrode SE and the drain electrode DE are positioned on the interlayer dielectric layer IN. The source electrode SE and the drain electrode DE are spaced from each other by a predetermined distance. The source electrode SE contacts one side of the semiconductor layer ACT through a source contact hole penetrating the interlayer dielectric layer IN. The drain electrode DE contacts the other side of the semiconductor layer ACT through a drain contact hole penetrating the interlayer dielectric layer IN.

[0060] Each of the source electrode SE and the drain electrode DE may be formed as a single layer or as a multilayer. When each of the source electrode SE and the drain electrode DE is formed as the single layer, each of the source electrode SE and the drain electrode DE may be formed of molybdenum (Mo), aluminum (Al), chrome (Cr), gold (Au), titanium (Ti), nickel (Ni), neodymium (Nd), copper (Cu), or a combination thereof. When each of the source electrode SE and the drain electrode DE is formed as the multilayer, each of the source electrode SE and the drain electrode DE may be formed as a double layer of Mo/Al—Nd, Mo/Al, Ti/Al or Cu/MoTi, or as a triple layer of Mo/Al—Nd/Mo, Mo/Al/Mo, Ti/Al/Ti or MoTi/Cu/MoTi.

[0061] A passivation layer PAS1 is positioned on the thin film transistor T. The passivation layer PAS1 protects the thin film transistor T and may be formed of silicon oxide (SiO_x), silicon nitride (SiN_x), or a multilayer thereof.

[0062] A planarization layer OC is positioned on the passivation layer PAS1. The planarization layer OC can reduce or planarize a height difference (or step coverage) of an underlying structure and may be formed of an organic material such as photo acryl, polyimide, benzocyclobutene-based resin, and acrylate-based resin. If necessary or desired, one of the passivation layer PAS1 and the planarization layer OC may be omitted.

[0063] The organic light emitting diode OLE and an auxiliary electrode AE are positioned on the planarization layer OC. The organic light emitting diode OLE includes an anode ANO, an organic light emitting layer OL, and a cathode CAT.

[0064] More specifically, the anode ANO is positioned on the planarization layer OC. The anode ANO is connected to the source electrode SE of the thin film transistor T through a contact hole penetrating the passivation layer PAS1 and the planarization layer OC. The anode ANO may include a reflective layer and thus serve as a reflective electrode. The reflective layer may be formed of aluminum (Al), copper (Cu), silver (Ag), palladium (Pd), nickel (Ni), or a combination thereof. For example, the reflective layer may be formed of Ag/Pd/Cu (APC) alloy. The anode ANO may be formed as a multilayer including a reflective layer.

[0065] The auxiliary electrode AE is positioned on the planarization layer OC. The auxiliary electrode AE may be formed of the same material as the anode ANO at the same layer as the anode ANO. In this instance, because a separate process for forming the auxiliary electrode AE does not need to be performed, the number of processes can be reduced. Hence, the manufacturing time and the manufacturing cost can be reduced, and product yield can be remarkably improved. As will be described later, the auxiliary electrode AE may function to receive a low potential power voltage

from the Evss line EVL through the conductive filler layer CFL and transfer the low potential power voltage to the cathode CAT.

[0066] A bank layer BN is positioned on the first substrate SUB1, on which the anode ANO and the auxiliary electrode AE are formed, and partitions pixels. The bank layer BN may be formed of an organic material such as polyimide, benzocyclobutene-based resin, and acrylate. A center portion of the anode ANO exposed by the bank layer BN may be defined as an emission region.

[0067] The bank layer BN may be configured to expose the center portion of the anode ANO and cover an edge of the anode ANO. The exposed portion of the anode ANO may be designed to have as large an area as possible, in order to sufficiently secure an aperture ratio. Further, the bank layer BN may be configured to expose a center portion of the auxiliary electrode AE and cover an edge of the auxiliary electrode AE. The exposed portion of the auxiliary electrode AE may be designed to have as large an area as possible, in order to sufficiently secure a contact area between the auxiliary electrode AE and the conductive filler layer CFL.

[0068] A first barrier BR1 is positioned on the first substrate SUB1 on which the bank layer BN is formed. The first barrier BR1 is positioned on the auxiliary electrode AE. The first barrier BR1 functions to physically divide each of the organic light emitting layer OL, the cathode CAT, and a protective layer PAS2 that will be formed later. In other words, each of the organic light emitting layer OL, the cathode CAT, and the protective layer PAS2 is disposed on the auxiliary electrode AE and is physically divided by the first barrier BR1. Hence, each of the organic light emitting layer OL, the cathode CAT, and the protective layer PAS2 may be discontinuously formed on the auxiliary electrode AE.

[0069] The bank layer BN and the planarization layer OC may be patterned to cover only the thin film transistor T and a storage capacitor Cst connected to the thin film transistor T inside the pixel. As shown in FIG. 3, the storage capacitor Cst may have a triple structure in which first to third capacitor electrodes are stacked. However, embodiments are not limited thereto. For example, the storage capacitor Cst may be implemented as a plurality of layers.

[0070] The organic light emitting layer OL is positioned on the first substrate SUB1 on which the first barrier BR1 is formed. The organic light emitting layer OL may be directly formed on a front surface of the first substrate SUB1. The organic light emitting layer OL is a layer, in which electrons and holes combine and emit light. The organic light emitting layer OL includes an emission layer EML and may further include one or more of a hole injection layer HIL, a hole transport layer HTL, an electron transport layer ETL, and an electron injection layer EIL. The emission layer EML may include a light emitting material that generates white light.

[0071] The organic light emitting layer OL emitting white light may have a multi-stack structure, for example, an n-stack structure, where n is an integer equal to or greater than 1. For example, 2-stack structure may include a charge generation layer CGL between the anode ANO and the cathode CAT and a first stack and a second stack respectively disposed on and under the charge generation layer CGL. Each of the first stack and the second stack includes an emission layer and may further include at least one common layer. The emission layer of the first stack and the

emission layer of the second stack may include emission materials of different colors, respectively.

[0072] The organic light emitting layer OL on the auxiliary electrode AE is physically divided by the first barrier BR1. The organic light emitting layer OL is divided by the first barrier BR1 and exposes at least a portion of the auxiliary electrode AE around the first barrier BR1. A portion of the organic light emitting layer OL divided by the first barrier BR1 is positioned on the first barrier BR1.

[0073] The cathode CAT is positioned on the organic light emitting layer OL. The cathode CAT may be widely formed on the front surface of the first substrate SUB1. The cathode CAT may be formed of a transparent conductive material such as indium tin oxide (ITO) and indium zinc oxide (IZO). Alternatively, the cathode CAT may be formed of a material, which is thin enough to transmit light, for example, magnesium (Mg), calcium (Ca), aluminum (Al), silver (Ag), or a combination thereof.

[0074] The cathode CAT on the auxiliary electrode AE is physically divided by the first barrier BR1. The cathode CAT is divided by the first barrier BR1 and exposes at least a portion of the auxiliary electrode AE around the first barrier BR1. A portion of the cathode CAT divided by the first barrier BR1 is positioned on the first barrier BR1. As will be described later, the cathode CAT may directly contact the auxiliary electrode AE and may be supplied with the low potential power voltage through the auxiliary electrode AE.

[0075] The cathode CAT covers the organic light emitting layer OL, and one end of the cathode CAT directly contacts the auxiliary electrode AE. Namely, one end of the cathode CAT, which is divided by the first barrier BR1 and is exposed, directly contacts an exposed upper surface of the auxiliary electrode AE. Such a structure may be implemented by a step coverage difference between materials forming the organic light emitting layer OL and the cathode CAT. For example, because the cathode CAT is made of a transparent conductive material having better step coverage than a formation material of the organic light emitting layer OL, the cathode CAT may be configured to directly contact the auxiliary electrode AE. Furthermore, in order to implement the structure, the organic light emitting layer OL and the cathode CAT may be formed using different methods. For example, the organic light emitting layer OL may be formed using a thermal deposition method, and the cathode CAT may be formed using a sputtering method. Hence, one end of the divided cathode CAT may be extended further than one end of the divided organic light emitting layer OL and may directly contact the auxiliary electrode AE.

[0076] The protective layer PAS2 is positioned on the cathode CAT. The protective layer PAS2 may be widely formed on the front surface of the first substrate SUB1. The protective layer PAS2 may be formed of a material such as silicon oxide (SiOx) and silicon nitride (SiNx).

[0077] More specifically, the protective layer PAS2 is positioned on the cathode CAT and can block the penetration of foreign material that may enter the organic light emitting diode OLE. For example, because the cathode CAT including a transparent conductive material is a crystalline component and cannot block the penetration of ions and moisture, ionic components or external impurities of an ionic liquid included in the conductive filler layer CFL may pass through the cathode CAT and may enter the organic light emitting layer OL. The first embodiment of the disclosure further includes the protective layer PAS2 on the organic

light emitting diode OLE and can block the penetration of foreign material that may enter the organic light emitting diode OLE. Hence, the first embodiment of the disclosure can prevent a reduction in lifespan of the organic light emitting diode OLE and a luminance reduction.

[0078] In addition, the protective layer PAS2 is positioned on the cathode CAT and can buffer or mitigate a stress applied to the cathode CAT when the first substrate SUB1 and the second substrate SUB2 are attached to each other. For example, because the cathode CAT including the transparent conductive material has brittle characteristics, the cathode CAT may easily crack due to an external force applied. The first embodiment of the disclosure further includes the protective layer PAS2 on the cathode CAT and can prevent a crack from being generated in the cathode CAT. Furthermore, the first embodiment of the disclosure can prevent the penetration of oxygen or moisture due to the crack.

[0079] The protective layer PAS2 on the auxiliary electrode AE is physically divided by the first barrier BR1. The protective layer PAS2 is divided by the first barrier BR1 and exposes at least a portion of the auxiliary electrode AE around the first barrier BR1. A portion of the protective layer PAS2 divided by the first barrier BR1 is positioned on the first barrier BR1. Hence, the portion of the organic light emitting layer OL, the portion of the cathode CAT, and the portion of the protective layer PAS2, each of which is divided by the first barrier BR1, are sequentially stacked on the first barrier BR1.

[0080] The Evss line EVL and a color filter CF are formed on the second substrate SUB2. A stacking order of the Evss line EVL and the color filter CF on the second substrate SUB2 may be changed. For example, the color filter CF may be formed after the Evss line EVL is formed, or the Evss line EVL may be formed after the color filter CF is formed.

[0081] The Evss line EVL includes a low resistance conductive material. For example, the Evss line EVL may be formed of molybdenum (Mo), aluminum (Al), chromium (Cr), gold (Au), titanium (Ti), nickel (Ni), neodymium (Nd), copper (Cu), or a combination thereof.

[0082] The Evss line EVL may include a low reflective conductive material. For example, the Evss line EVL is formed of the low reflective conductive material and thus can prevent visibility from being reduced by the reflection of external light. Thus, a display device according to embodiments of the disclosure does not need to include a separate component for shielding (or absorbing) light incident from outside, like a polarizing film.

[0083] The Evss line EVL may function as a black matrix. Therefore, the Evss line EVL can prevent a defect of color mixture from occurring between neighboring pixels. The Evss line EVL may be disposed corresponding to a non-emission region so as to expose at least the emission region. Further, the first embodiment of the disclosure can use the Evss line EVL as the black matrix and thus does not need to additionally perform a separate process for forming the black matrix. Therefore, the first embodiment of the disclosure can further reduce the number of processes compared to a related art structure, and thus can reduce the manufacturing time and the manufacturing cost and remarkably improve product yield.

[0084] The color filter CF may include red (R), blue (B), and green (G) color filters. The pixel may include subpixels emitting red, blue, and green light, and the color filters CF

may be respectively assigned to the corresponding subpixels. The red, blue, and green color filters CF may be partitioned by the Evss line EVL. If necessary or desired, the pixel may further include a white (W) subpixel.

[0085] The conductive filler layer CFL is interposed between the first substrate SUB1 and the second substrate SUB2 and includes a conductive medium. The conductive filler layer CFL may be formed by dispersing conductive fillers in a solvent. Alternatively, the conductive filler layer CFL may include a conductive solvent. For example, the conductive filler layer CFL may include at least one of a conductive polymer, such as poly(3,4-ethylenedioxythiophene) (PEDOT), and an ionic liquid. However, embodiments are not limited thereto.

[0086] The attachment distance between the first substrate SUB1 and the second substrate SUB2 may be appropriately selected depending on viscosity of the conductive filler layer CFL. Because the embodiment of the disclosure uses the conductive fillers having lower viscosity than non-conductive fillers, the distance between the first substrate SUB1 and the second substrate SUB2 can be reduced. Hence, the embodiment of the disclosure can secure a wide viewing angle and a high aperture ratio.

[0087] The cathode CAT of the first substrate SUB1 and the Evss line EVL of the second substrate SUB2 are electrically connected through the conductive filler layer CFL. Thus, the low potential power voltage is applied to both the cathode CAT and the Evss line EVL.

[0088] More specifically, in the embodiment of the disclosure, because the protective layer PAS2 is interposed between the conductive filler layer CFL and the cathode CAT, it is difficult to bring the conductive filler layer CFL into direct contact with the cathode CAT without using the first barrier BR1. Referring to FIG. 4, the embodiment of the disclosure includes the first barrier BR1 and thus can expose at least a portion of the auxiliary electrode AE while physically dividing each of the organic light emitting layer OL, the cathode CAT, and the protective layer PAS2. The exposed portion of the auxiliary electrode AE can directly contact the conductive filler layer CFL to receive the low potential power voltage from the Evss line EVL of the second substrate SUB2, and can also directly contact the cathode CAT to transfer the received low potential power voltage to the cathode CAT.

[0089] The first embodiment of the disclosure can reduce a voltage variation (or voltage deviation) depending on a position by connecting the Evss line EVL formed of the low resistance conductive material to the cathode CAT. Hence, the first embodiment of the disclosure can reduce non-uniformity of luminance or a luminance variation (or luminance variation).

[0090] The first embodiment of the disclosure does not need to separately assign an area for forming the Evss line EVL and an area for connecting the Evss line EVL and the cathode CAT to the thin film transistor array substrate, as in the related art. Therefore, the first embodiment of the disclosure can be easily applied to a high-resolution display having a high pixel per inch (PPI) and can remarkably improve a degree of design freedom.

[0091] With reference to FIG. 5, an example of a shape of a barrier according to an embodiment of the disclosure is described below. FIG. 5 is cross-sectional views schematically illustrating a shape of a barrier.

[0092] A barrier BR may be formed as a double layer including a first structure B1 and a second structural B2. The first structure B1 may be disposed on the second structural B2, and an edge of the first structure B1 may have an eaves shape. Namely, the edge of the first structure B1 may protrude from an edge of the second structural B2 to the outside by a predetermined distance RR. The distance RR between the edge of the first structure B1 and the edge of the second structural B2 may be properly selected so that the barrier BR can expose at least a portion of an auxiliary electrode AE while dividing each of an organic light emitting layer, a cathode, and a protective layer. In other words, each of the organic light emitting layer OL (see FIG. 3), the cathode CAT (see FIG. 3), and the protective layer PAS2 (see FIG. 3) is patterned to expose at least a portion of the auxiliary electrode AE while being divided around the barrier BR due to the predetermined distance RR between the edge of the first structure B1 and the edge of the second structural B2. The first structure B1 may have a reverse taper shape as shown in portion (a) of FIG. 5 and may have a taper shape as shown in portion (b) of FIG. 5. The first structure B1 and the second structural B2 may be formed of different materials.

[0093] A barrier BR may be formed as a single layer including a first structure B1. In this instance, the first structure B1 has a shape in which an edge of an upper side protrudes from an edge of a lower side to the outside by a predetermined distance RR. For example, the first structure B1 may have a reverse taper shape as shown in portion (c) of FIG. 5. Namely, a vertical cross-sectional shape of the first structure B1 may have a trapezoidal shape, the upper side may have a length longer than the lower side, and one end of the upper side may protrude from one end of the lower side to the outside by the predetermined distance RR. The distance RR between one end of the upper side and one end of the lower side may be properly selected so that the barrier BR can expose at least a portion of an auxiliary electrode AE while dividing each of an organic light emitting layer, a cathode, and a protective layer. In other words, each of the organic light emitting layer OL (see FIG. 3), the cathode CAT (see FIG. 3), and the protective layer PAS2 (see FIG. 3) is patterned to expose at least a portion of the auxiliary electrode AE while being divided around the barrier BR due to the distance RR between one end of the upper side and one end of the lower side.

Second Embodiment

[0094] FIG. 6 is a cross-sectional view of an OLED display according to a second embodiment of the disclosure. FIG. 7 is an enlarged view of an area AR2 shown in FIG. 6. FIG. 8 illustrates a position relationship of a cathode, a protective layer, and a contact electrode. Description of structures and components identical or equivalent to those illustrated in the first embodiment is omitted in the second embodiment.

[0095] The second embodiment of the disclosure is characterized in that a conductive filler layer CFL and a cathode CAT are electrically connected through an auxiliary electrode AE to form a low potential power voltage supply path. On the other hand, the first embodiment of the disclosure is configured such that the conductive filler layer CFL and the auxiliary electrode AE are connected only in a partial area to which the auxiliary electrode AE is exposed. Hence, the first embodiment of the disclosure may have a problem that it is

difficult to transfer a low potential power voltage along a determined path due to a contact resistance resulting from a narrow contact area. Further, when an exposed portion of the auxiliary electrode AE is formed narrowly, the exposed portion may be shielded due to a foreign material, etc. Hence, the auxiliary electrode AE cannot perform its function as the low potential power voltage supply path and/or a component capable of reducing a voltage variation depending on a position.

[0096] To solve the above-described problem, the OLED display according to the second embodiment of the disclosure further includes a contact electrode TE with reference to FIGS. 6 and 7. The contact electrode TE is positioned on a protective layer PAS2. The contact electrode TE may be widely formed on a front surface of a first substrate SUB1. The contact electrode TE may be formed of a transparent conductive material such as indium tin oxide (ITO) and indium zinc oxide (IZO). Alternatively, the contact electrode TE may be formed of a material, which is thin enough to transmit light, for example, magnesium (Mg), calcium (Ca), aluminum (Al), silver (Ag), or a combination thereof.

[0097] The contact electrode TE is disposed on the auxiliary electrode AE and is physically divided by a first barrier BR1. The contact electrode TE is divided by the first barrier BR1 and exposes at least a portion of the auxiliary electrode AE around the first barrier BR1. A portion of the contact electrode TE divided by the first barrier BR1 is positioned on the first barrier BR1.

[0098] The contact electrode TE covers the protective layer PAS2, and one end of the contact electrode TE directly contacts the auxiliary electrode AE. Namely, one end of the contact electrode TE, which is divided by the first barrier BR1 and is exposed, directly contacts an exposed upper surface of the auxiliary electrode AE. The contact electrode TE directly contacts the auxiliary electrode AE and thus can supply the low potential power voltage received from the conductive filler layer CFL to the auxiliary electrode AE.

[0099] Hence, the second embodiment of the disclosure can supply the low potential power voltage to the pixels through a plurality of paths. For example, the second embodiment of the disclosure may supply the low potential power voltage to the pixels through a power path connecting the conductive filler layer CFL, the auxiliary electrode AE, and the cathode CAT. Further, the second embodiment of the disclosure may supply the low potential power voltage to the pixels through a power path connecting the conductive filler layer CFL, the contact electrode TE, the auxiliary electrode AE, and the cathode CAT.

[0100] The contact electrode TE is widely formed on the first substrate SUB1 and directly contacts the conductive filler layer CFL in a wide area. Because the second embodiment of the disclosure can secure a sufficient contact area between the contact electrode TE and the conductive filler layer CFL, the low potential power voltage can be easily transferred from the conductive filler layer CFL to the cathode CAT. The second embodiment of the disclosure sufficiently secures the contact area and thus can solve the problem of the contact resistance that may occur in the first embodiment.

[0101] Referring to portion (a) of FIG. 8, the contact electrode TE further protrudes toward the barrier than the protective layer PAS2 and directly contacts the auxiliary electrode AE. In this instance, one end of the contact electrode TE and one of the cathode CAT may directly

contact each other. More specifically, the protective layer PAS2 on the cathode CAT may be formed to expose one end of the cathode CAT, and the exposed end of the cathode CAT may directly contact the contact electrode TE on the protective layer PAS2. Hence, the contact electrode TE can directly transfer the low potential power voltage received from the conductive filler layer CFL to the cathode CAT.

[0102] In this instance, because various power paths can be secured, the second embodiment of the disclosure can more easily supply the low potential power voltage to the pixels through the various power paths. Examples of the power paths include a power path connecting the conductive filler layer CFL, the auxiliary electrode AE, and the cathode CAT, a power path connecting the conductive filler layer CFL, the contact electrode TE, the auxiliary electrode AE, and the cathode CAT, and a power path connecting the conductive filler layer CFL, the contact electrode TE, and the cathode CAT.

[0103] Referring to portion (b) of FIG. 8, the protective layer PAS2 may completely cover the cathode CAT. Namely, as one end of the protective layer PAS2 directly contacts the auxiliary electrode AE, the protective layer PAS2 may completely cover the cathode CAT. Because the protective layer PAS2 is configured to completely cover the cathode CAT, the protective layer PAS2 can efficiently block the penetration of foreign materials that may enter an organic light emitting diode OLE. In this instance, the contact electrode CAT and the contact electrode TE are physically spaced from each other with the protective layer PAS2 interposed therebetween.

[0104] The structure shown in FIG. 8 may be implemented by properly controlling process conditions. For example, the cathode CAT and the contact electrode TE may be formed of the same material and be formed using a mask having openings that have the same area. In this instance, the structure shown in FIG. 8 may be implemented by selectively controlling process parameters such as electric power and a pressure.

[0105] A supply path of the low potential power voltage generated by a power generator (not shown) is described in detail below. FIGS. 9 and 10 illustrate an example of configuration of a power supply unit.

[0106] Referring to FIG. 9, the OLED display according to the second embodiment of the disclosure further includes a connection member LM attached to at least one side of the display panel, particularly, at least one side of the first substrate SUB1. The connection member LM may be a chip-on film (COF). However, embodiments are not limited thereto.

[0107] The first substrate SUB1 includes a low potential power voltage pad (hereinafter referred to as "Evss pad") EVP and a power electrode POE. The Evss pad EVP is disposed outside a sealant SL and is electrically connected to the connection member LM. The power electrode POE is disposed inside the sealant SL and is electrically connected to the conductive filler layer CFL.

[0108] The Evss pad EVP receives the low potential power voltage generated by the power generator (not shown) through the connection member LM and transfers the received low potential power voltage to the power electrode POE. The power electrode POE then transfers the low potential power voltage to the conductive filler layer CFL.

[0109] Namely, the connection member LM, the Evss pad EVP, the power electrode POE, the conductive filler layer

CFL, and the cathode CAT may be electrically connected to form a low potential power voltage supply path, and/or the connection member LM, the Evss pad EVP, the power electrode POE, the conductive filler layer CFL, the Evss line EVL, and the cathode CAT may be electrically connected to form a low potential power voltage supply path.

[0110] More specifically, the Evss pad EVP includes at least one pad electrode. When a plurality of pad electrodes is used, the pad electrodes may be disposed at different layers with at least one insulating layer interposed therebetween and may be electrically connected through a pad contact hole penetrating the at least one insulating layer. For example, as shown in FIG. 9, the Evss pad EVP may include a first pad electrode PE1 and a second pad electrode PE2 that are disposed at different layers with a passivation layer PAS1 interposed therebetween, and the first pad electrode PE1 and the second pad electrode PE2 may be connected to each other through a first pad contact hole PH1 penetrating the passivation layer PAS1. Hereinafter, the embodiment of the disclosure describes a case where the Evss pad EVP includes the first pad electrode PE1 and the second pad electrode PE2 as an example, for convenience of explanation.

[0111] The first pad electrode PE1 is disposed outside the sealant SL and is exposed to the outside. The exposed first pad electrode PE1 may be attached to the connection member LM. The first pad electrode PE1 and the connection member LM may be attached to each other through an anisotropic conductive film (ACF) layer (not shown) interposed between them.

[0112] The second pad electrode PE2 is extended to the inside of the sealant SL and is electrically connected to the power electrode POE. In this instance, the second pad electrode PE2 may contact the power electrode POE through a second pad contact hole PH2 penetrating the passivation layer PAS1. FIG. 9 illustrates that the second pad electrode PE2 and the power electrode POE are disposed with only the passivation layer PAS1 interposed therebetween, by way of example. However, embodiments are not limited thereto. For example, the second pad electrode PE2 and the power electrode POE may be disposed at different layers with the passivation layer PAS1 and a planarization layer OC interposed therebetween and may be electrically connected to each other through a contact hole penetrating the passivation layer PAS1 and the planarization layer OC.

[0113] The power electrode POE may be formed together when an anode ANO is formed. Namely, the power electrode POE may be formed of the same material as the anode ANO and the auxiliary electrode AE. However, embodiments are not limited thereto.

[0114] At least a portion of the power electrode POE may be exposed and may directly contact the conductive filler layer CFL. In order to expose at least a portion of the power electrode POE, respective areas of layers widely formed on the front surface of the first substrate SUB1 may be controlled. The layers, of which the area is controllable, are layers (e.g., an organic light emitting layer OL, the cathode CAT, and the protective layer PAS2) formed after the formation of the power electrode POE.

[0115] More specifically, the above layers are formed using a frame-shaped open mask (not shown) having an opening. An area of the opening of the open mask may correspond to an area occupied by the above layers on the first substrate SUB1. Thus, at least a portion of the power electrode POE can be exposed by controlling the area of the

opening of the open mask. The exposed portion of the power electrode POE may directly contact the conductive filler layer CFL and supply the low potential power voltage to the conductive filler layer CFL. Hence, a power supply path connecting the connection member LM, the Evss pad EVP, and the conductive filler layer CFL may be formed.

[0116] The cathode CAT on the power electrode POE may cover the organic light emitting layer OL, and one end of the cathode CAT may directly contact the power electrode POE. Namely, one end of the cathode CAT may directly contact an exposed upper surface of the power electrode POE. Hence, a power supply path connecting the connection member LM, the Evss pad EVP, and the cathode CAT may be formed.

[0117] Further, one end of the contact electrode TE on the power electrode POE may directly contact the power electrode POE. Namely, one end of the contact electrode TE may directly contact the exposed upper surface of the power electrode POE. Hence, a power supply path connecting the connection member LM, the Evss pad EVP, and the contact electrode TE may be formed.

[0118] As another example, referring to FIG. 10, a second barrier BR2 may be formed on the power electrode POE. The second barrier BR2 may be formed together when the first barrier BR1 is formed. Namely, the second barrier BR2 may be formed of the same material as the first barrier BR1 and may have the same shape as the first barrier BR1. The second barrier BR2 functions to physically divide each of the organic light emitting layer OL, the cathode CAT, the protective layer PAS2, and the contact electrode TE which will be formed later. In other words, each of the organic light emitting layer OL, the cathode CAT, the protective layer PAS2, and the contact electrode TE is disposed on the power electrode POE and is physically divided by the second barrier BR2. Hence, each of the organic light emitting layer OL, the cathode CAT, the protective layer PAS2, and the contact electrode TE may be discontinuously formed on the power electrode POE.

[0119] In the embodiment of the disclosure, the organic light emitting layer OL, the cathode CAT, the protective layer PAS2, and the contact electrode TE are disposed inside the sealant SL and on the entire surface of the first substrate SUB1 and may completely cover the power electrode POE positioned inside the sealant SL. In this instance, the power electrode POE and the conductive filler layer CFL cannot be electrically connected to each other, and the power electrode POE and the cathode CAT cannot be electrically connected to each other.

[0120] The second embodiment of the disclosure forms the second barrier BR2 on the power electrode POE and thus can expose at least a portion of the power electrode POE while physically dividing each of the organic light emitting layer OL, the cathode CAT, the protective layer PAS2, and the contact electrode TE on the power electrode POE. A portion of the organic light emitting layer OL, a portion of the cathode CAT, a portion of the protective layer PAS2, and a portion of the contact electrode TE, each of which is divided by the second barrier BR2, are sequentially stacked on the second barrier BR2.

[0121] An exposed portion of the power electrode POE directly contacts the conductive filler layer CFL and supplies the low potential power voltage to the conductive filler layer CFL. Hence, a power supply path connecting the connection member LM, the Evss pad EVP, and the conductive filler layer CFL may be formed.

[0122] One end of the cathode CAT on the power electrode POE may directly contact the power electrode POE. Namely, one end of the cathode CAT, which is divided by the second barrier BR2 and is exposed, may directly contact the exposed upper surface of the power electrode POE. Hence, a power supply path connecting the connection member LM, the Evss pad EVP, and the cathode CAT may be formed.

[0123] Further, one end of the contact electrode TE on the power electrode POE may directly contact the power electrode POE. Namely, one end of the contact electrode TE, which is divided by the second barrier BR2 and is exposed, may directly contact the exposed upper surface of the power electrode POE. Hence, a power supply path connecting the connection member LM, the Evss pad EVP, and the contact electrode TE may be formed.

Third Embodiment

[0124] FIG. 11 is a cross-sectional view of an OLED display according to a third embodiment of the disclosure. FIG. 12 illustrates examples of configuration in which a color filter is formed on a first substrate. Description of structures and components identical or equivalent to those illustrated in the first and second embodiments is omitted in the third embodiment.

[0125] Referring to FIG. 11, an OLED display according to a third embodiment of the disclosure includes a display panel including a first substrate SUB1 and a second substrate SUB2 facing each other and a conductive filler layer CFL between the first substrate SUB1 and the second substrate SUB2. The first substrate SUB1 is a thin film transistor array substrate on which a thin film transistor T and an organic light emitting diode OLE connected to the thin film transistor T are formed. The second substrate SUB2 is a substrate on which an Evss line EVL is formed.

[0126] Unlike the first and second embodiments, a color filter CF according to the third embodiment is formed on the first substrate SUB1. Namely, the thin film transistor T, the organic light emitting diode OLE, a protective layer PAS2, a contact electrode TE, and the color filter CF are formed on the first substrate SUB1. The color filters CF may be respectively assigned to corresponding pixels.

[0127] For example, as shown in portion (a) of FIG. 12, the color filter CF may be formed on the contact electrode TE. In this instance, a distance between the color filter CF and an organic light emitting layer OL can be further reduced compared to the first and second embodiments. Therefore, a viewing angle can increase, and a sufficient aperture ratio can be secured.

[0128] As another example, as shown in portion (b) of FIG. 12, the color filter CF may be interposed between a cathode CAT and the protective layer PAS2. In this instance, a contact area between the contact electrode TE and the conductive filler layer CFL can be more sufficiently secured, compared to the structure on which the color filter CF is formed on the contact electrode TE.

[0129] As another example, as shown in portion (c) of FIG. 12, the color filter CF may be interposed between the contact electrode TE and the protective layer PAS2. As the protective layer PAS2 is further formed on the cathode CAT, the organic light emitting diode OLE is not exposed to an environment provided by a process for forming the color filter CF. Hence, the deterioration of the organic light emitting diode OLE can be minimized or reduced.

Fourth Embodiment

[0130] FIG. 13 is a cross-sectional view of an OLED display according to a fourth embodiment of the disclosure. Description of structures and components identical or equivalent to those illustrated in the first and second embodiments is omitted in the fourth embodiment.

[0131] Referring to FIG. 13, an OLED display according to a fourth embodiment of the disclosure includes a display panel including a first substrate SUB1 and a second substrate SUB2 facing each other and a conductive filler layer CFL between the first substrate SUB1 and the second substrate SUB2. The first substrate SUB1 is a thin film transistor array substrate on which a thin film transistor T and an organic light emitting diode OLE connected to the thin film transistor T are formed. The second substrate SUB2 is a substrate on which an Evss line EVL is formed.

[0132] The Evss line EVL and an auxiliary Evss line (or referred to as "auxiliary power line") AEVL are formed on the second substrate SUB2. A color filter CF may be positioned on the second substrate SUB2 as in the first and second embodiments and may be positioned on the first substrate SUB1 as in the third embodiment.

[0133] One surface of the auxiliary Evss line AEVL directly contacts the Evss line EVL, and the other surface of the auxiliary Evss line AEVL directly contacts the conductive filler layer CFL. The auxiliary Evss line AEVL is a power line for increasing a contact area between the Evss line EVL and the conductive filler layer CFL and may have an area larger than the Evss line EVL. The auxiliary Evss line AEVL may be interposed between the Evss line EVL and the conductive filler layer CFL. The auxiliary Evss line AEVL may be formed to cover the Evss line EVL and the color filter CF and may be widely formed on a front surface of the second substrate SUB2 including an emission region. The auxiliary Evss line AEVL may be formed of a transparent conductive material such as indium tin oxide (ITO) and indium zinc oxide (IZO).

[0134] Because the fourth embodiment of the disclosure can sufficiently secure the contact area between the Evss line EVL and the conductive filler layer CFL using the auxiliary Evss line AEVL, the fourth embodiment of the disclosure can minimize or reduce a contact failure between the Evss line EVL and the conductive filler layer CFL. Further, the fourth embodiment of the disclosure can more efficiently reduce a voltage variation depending on a position and thus can reduce non-uniformity of luminance or a luminance variation.

[0135] It will be apparent to those skilled in the art that various modifications and variations can be made in the organic light emitting diode display of the present disclosure without departing from the technical idea or scope of the disclosure. Thus, it is intended that the present disclosure cover the modifications and variations of this disclosure provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. An organic light emitting diode display, comprising:
 - a first substrate including an organic light emitting diode;
 - a second substrate including a power line supplied with a power voltage, the second substrate facing the first substrate; and
 - a conductive filler layer interposed between the first substrate and the second substrate, the conductive filler layer including a conductive medium,

wherein the first substrate includes:
 an auxiliary electrode;
 a first barrier disposed on the auxiliary electrode;
 a cathode included in the organic light emitting diode and physically divided by the first barrier, the cathode exposing at least a portion of the auxiliary electrode, one end of the cathode directly contacting the auxiliary electrode;
 a contact electrode disposed on the cathode and physically divided by the first barrier, the contact electrode exposing at least a portion of the auxiliary electrode, one end of the contact electrode directly contacting the auxiliary electrode; and
 a protective layer interposed between the cathode and the contact electrode.

2. The organic light emitting diode display of claim 1, wherein the contact electrode directly contacts the conductive filler layer and is electrically connected to the cathode through the auxiliary electrode.

3. The organic light emitting diode display of claim 1, wherein the protective layer on the cathode exposes at least a portion of one end of the cathode,
 wherein the contact electrode on the protective layer directly contacts the exposed portion of the cathode.

4. The organic light emitting diode display of claim 1, wherein the cathode and the contact electrode are spaced from each other with the protective layer interposed therebetween.

5. The organic light emitting diode display of claim 1, wherein the conductive filler layer directly contacts the exposed portion of the auxiliary electrode.

6. The organic light emitting diode display of claim 1, further comprising:
 a sealant disposed at an edge of the first substrate and an edge of the second substrate, the conductive filler layer being accommodated inside the sealant; and
 a power electrode disposed on the first substrate and inside the sealant, the power electrode receiving the power voltage from a power generator,
 wherein at least a portion of the power electrode directly contacts the conductive filler layer, and
 wherein the power electrode is electrically connected to the power line through the conductive filler layer.

7. The organic light emitting diode display of claim 1, further comprising:
 a sealant disposed at an edge of the first substrate and an edge of the second substrate, the conductive filler layer being accommodated inside the sealant;
 a power electrode disposed on the first substrate and inside the sealant, the power electrode receiving the power voltage from a power generator; and
 a second barrier disposed on the power electrode,
 wherein the cathode is divided by the second barrier and exposes at least a portion of the power electrode,
 wherein the protective layer is divided by the second barrier and exposes at least a portion of the power electrode,
 wherein the contact electrode is divided by the second barrier and exposes at least a portion of the power electrode,
 wherein the power electrode is electrically connected to an exposed portion of the power line through the conductive filler layer.

8. The organic light emitting diode display of claim 7, wherein one end of the cathode directly contacts the power electrode,

wherein one end of the contact electrode directly contacts the power electrode.

9. The organic light emitting diode display of claim 1, wherein the second substrate further includes color filters, wherein the color filters are partitioned by the power line.

10. The organic light emitting diode display of claim 1, wherein the first substrate further includes color filters respectively assigned to pixels,

wherein the color filters are disposed on the contact electrode.

11. The organic light emitting diode display of claim 1, wherein the first substrate further includes color filters respectively assigned to pixels,

wherein the color filters are interposed between the cathode and the protective layer.

12. The organic light emitting diode display of claim 1, wherein the first substrate further includes color filters respectively assigned to pixels,

wherein the color filters are interposed between the protective layer and the contact electrode.

13. The organic light emitting diode display of claim 1, wherein each of the first substrate and the second substrate includes an emission region, to which light from the organic light emitting diode is emitted, and a non-emission region outside the emission region,

wherein the power line is disposed in the non-emission region.

14. The organic light emitting diode display of claim 13, wherein the second substrate further includes an auxiliary power line, of which at least a portion of one surface directly contacts the power line, and another surface opposite the one surface directly contacts the conductive filler layer.

15. The organic light emitting diode display of claim 14, wherein the auxiliary power line has an area larger than the power line.

16. The organic light emitting diode display of claim 14, wherein the auxiliary power line includes a transparent conductive material.

17. An organic light emitting diode display comprising:
 a first substrate including an organic light emitting diode;
 a second substrate including a power line supplied with a power voltage, the second substrate facing the first substrate; and

a conductive filler layer interposed between the first substrate and the second substrate, the conductive filler layer including a conductive medium,

wherein the first substrate includes:

an auxiliary electrode;

a first barrier disposed on the auxiliary electrode;

a cathode included in the organic light emitting diode, the cathode comprising a first portion covering an upper surface of the first barrier and a second portion disconnecting with the first portion and not covering the first barrier, the cathode exposing at least a portion of the auxiliary electrode, wherein the second portion of the cathode extends such that one end thereof directly contacts the exposed portion of the auxiliary electrode;

a contact electrode disposed on the first portion and the second portion of the cathode, respectively, to form a first portion and a second portion of the contact electrode, the contact electrode exposing at least a portion

of the auxiliary electrode, wherein the second portion of the contact electrode extends such that one end thereof directly contacts the exposed portion of the auxiliary electrode; and

a protective layer interposed between the cathode and the contact electrode.

18. The organic light emitting diode display of item 17, further comprising:

a sealant disposed at an edge of the first substrate and an edge of the second substrate, the conductive filler layer being accommodated inside the sealant;

a power electrode disposed on the first substrate and inside the sealant, the power electrode receiving the power voltage from a power generator; and

a second barrier disposed on the power electrode, wherein the second portion of the cathode is further divided by the second barrier to form a third portion

covering an upper surface of the second barrier and a forth portion disconnecting with the third portion and not covering the second barrier, the cathode exposing at least a portion of the power electrode, wherein the fourth portion of the cathode extends such that one end thereof directly contacts the exposed portion of the power electrode,

wherein both the protective layer and the contact electrode are divided by the second barrier in a same way as the cathode to form a third portion and a fourth portion and exposes at least a portion of the power electrode,

wherein the exposed portion of the power electrode is electrically connected to the power line through the conductive filler layer.

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专利名称(译)	有机发光二极管显示器		
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[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
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其他公开文献	US10566407		
外部链接	Espacenet USPTO		

摘要(译)

公开了一种有机发光二极管显示器。有机发光二极管显示器包括：第一基板，包括有机发光二极管；第二基板，包括供应有电源电压并面向第一基板的电源线；以及导电填充层，位于第一基板和第二基板之间。第一基板包括辅助电极，辅助电极上的第一屏障，被第一屏障物理分隔并暴露至少一部分辅助电极的阴极，设置在阴极上的接触电极，被第一屏障物理地分开，并且暴露至少一部分辅助电极，以及阴极和接触电极之间的保护层。阴极的一端直接接触辅助电极，接触电极的一端直接接触辅助电极。

